

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



In re Applicant:

Arkadiy MORGENSHTEIN et al

Serial No.: 10/825,123

Filed: April 16, 2004

Group Art Unit: 4128

For: ION CONCENTRATION
TRANSISTOR AND DUAL-
MODE SENSORS (amended)

Attorney
Docket: 27238

Examiner: John C. BALL

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

DECLARATION UNDER 37 CFR 1.131

Sir:

I, Yael NEMIROVSKY of 7 Golda St., Haifa, Israel, declare as follows:

1. I am a joint inventor of the invention disclosed and claimed in the above-identified application;

2. I supervised the Research Thesis titled "Design an Methodology of ISFET (Ion Sensitive Field Effect Transistor) Microsystems for Bio-Telemetry" authored and submitted by Arkady Morgenshtein. The work on the Thesis was jointly performed by Arkady Morgenshtein, Prof. Uri Dinnar and me. Arkady Morgenshtein is named as an author of the Thesis as is customary for Master students in their Research Thesis; and

I declare that all statements made herein of our knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements are made with the knowledge that willfully false statements are punishable by fine or imprisonment under 18 U.S.C. Section 1001 and that any such statement may jeopardize the validity of the subject application or any patent issued thereon.

Yael Nemirowsky
Yael NEMIROVSKY

October 3, 2008
Date: October 3, 2008